

RoHS

COMPLIANT

# Phase Control Thyristors (Stud Version), 230 A



PRIMARY CHARACTERISTICS				
I <sub>T(AV)</sub>	230 A			
$V_{DRM}/V_{RRM}$	1400 V, 1600 V			
$V_{TM}$	1.55 V			
I <sub>GT</sub>	150 mA			
$T_J$	-40 °C to +125 °C			
Package	TO-93 (TO-209AB)			
Circuit configuration	Single SCR			

#### **FEATURES**

- · Center amplifying gate
- International standard case TO-93 (TO-209AB)
- · Hermetic metal case with ceramic insulator
- Compression bonded encapsulation for heavy duty operations such as severe thermal cycling
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **TYPICAL APPLICATIONS**

- · DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
1		230	A		
I <sub>T(AV)</sub>	T <sub>C</sub>	85	°C		
I <sub>T(RMS)</sub>		360	A		
	50 Hz	5700	Δ.		
ITSM	60 Hz	5970	A		
10.	50 Hz	163	kA <sup>2</sup> s		
I <sup>2</sup> t	60 Hz	149	- KA-S		
V <sub>DRM</sub> /V <sub>RRM</sub>		1400 to 1600	V		
tq	Typical	100	μs		
T <sub>J</sub>		-40 to +125	°C		

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V <sub>DRM</sub> /V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$I_{DRM}/I_{RRM}$ MAXIMUM AT $T_J = T_J$ MAXIMUM mA				
VS-ST230S	14	1400	1500	30				
V3-312303	16	1600	1700	30				



ABSOLUTE MAXIMUM RATINGS	S					
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average on-state current	I <sub>T(AV)</sub>	180° conduction, half sine wave			230	A °C
at case temperature					85	30
Maximum RMS on-state current	I <sub>T(RMS)</sub>	DC at 78 °C	case temperat	ure	360	
		t = 10 ms	No voltage		5700	
Maximum peak, one-cycle	ı	t = 8.3  ms	reapplied		5970	А
non-repetitive surge current	I <sub>TSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		4800	
		t = 8.3 ms	reapplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	5000	
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	t = 10 ms	No voltage		163	- kA <sup>2</sup> s
		t = 8.3 ms	reapplied		148	
		t = 10 ms	100 % V <sub>RRM</sub>		115	
		t = 8.3 ms	reapplied		105	
Maximum I <sup>2</sup> √t for fusing	I²√t	t = 0.1 to 10	t = 0.1 to 10 ms, no voltage reapplied			kA²√s
Low level value of threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x π	$x I_{T(AV)} < I < \pi x$	I <sub>T(AV)</sub> ), T <sub>J</sub> = T <sub>J</sub> maximum	0.92	V
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)})$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			V
Low level value of on-state slope resistance	r <sub>t1</sub>	(16.7 % x π	(16.7 % x $\pi$ x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ maximum			<b>m</b> 0
High level value of on-state slope resistance	r <sub>t2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.81	mΩ
Maximum on-state voltage	V <sub>TM</sub>	$I_{pk} = 720 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$			1.55	V
Maximum holding current	I <sub>H</sub>	T _ 05 °C	anada ayanlı 1	2.V registive lead	600	mΛ
Maximum (typical) latching current	ΙL	T <sub>J</sub> = 25 °C, anode supply 12 V resistive load		1000 (300)	mA	

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega$ , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/µs
Typical delay time	t <sub>d</sub>	Gate current 1 A, $dl_g/dt = 1$ A/ $\mu$ s $V_d = 0.67 \% V_{DRM}$ , $T_J = 25 °C$	1.0	
Typical turn-off time	t <sub>q</sub>	$\begin{array}{l} I_{TM}=300~A,~T_J=T_J~maximum,~dI_F/dt=20~A/\mu s,\\ V_R=50~V,~dV/dt=20~V/\mu s,~gate~0~V~100~\Omega,~t_p=500~\mu s \end{array}$	100	μs

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	T <sub>J</sub> = T <sub>J</sub> maximum linear to 80 % rated V <sub>DRM</sub>	500	V/µs
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub> , I <sub>DRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	30	mA



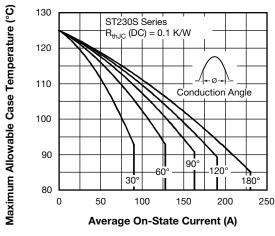
TRIGGERING						
DADAMETED	CVMPOL	TEGT COMPITIONS		VALUES		LINUTO
PARAMETER	SYMBOL	<b>"</b>	EST CONDITIONS	TYP.	MAX.	UNITS
Maximum peak gate power	P <sub>GM</sub>	$T_J = T_J$ maximum,	$t_p \leq 5 \; ms$	10.0		W
Maximum average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	VV
Maximum peak positive gate current	I <sub>GM</sub>	$T_J = T_J$ maximum,	$t_p \leq 5 \ ms$	3	.0	Α
Maximum peak positive gate voltage	+ V <sub>GM</sub>	T - T movimum	T. T ' I		20	
Maximum peak negative gate voltage	- V <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms		5.0		V
	I <sub>GT</sub>	T <sub>J</sub> = - 40 °C	Maximum required gate trigger/- current/voltage are the lowest value which will trigger all units 12	180	-	
DC gate current required to trigger		T <sub>J</sub> = 25 °C		90	150	mA
		T <sub>J</sub> = 125 °C		40	-	
		T <sub>J</sub> = - 40 °C		2.9	-	
DC gate voltage required to trigger	$V_{GT}$	T <sub>J</sub> = 25 °C	V anode to cathode applied	1.8	3.0	V
		T <sub>J</sub> = 125 °C		1.2	-	1
DC gate current not to trigger	I <sub>GD</sub>		Maximum gate current/voltage not	10		mA
DC gate voltage not to trigger	V <sub>GD</sub>	$T_J = T_J  \text{maximum}  \text{to trigger is the maximum value} \\ \text{which will not trigger any unit with} \\ \text{rated}  V_{DRM}  \text{anode to cathode} \\ \text{applied}$		0.	25	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum operating junction temperature range	TJ		-40 to 125	°C	
Maximum storage temperature range	T <sub>Stg</sub>		-40 to 150		
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	0.10	12.001	
Maximum thermal resistance, case to heatsink	R <sub>thC-hs</sub>	Mounting surface, smooth, flat and greased	0.04	- K/W	
Mounting torque + 10.0/		Non-lubricated threads	31 (275)	N·m	
Mounting torque, ± 10 %		Lubricated threads	24.5 (210)	(lbf ⋅ in)	
Approximate weight			280	g	
Case style		See dimensions - link at the end of datasheet	TO-93 (TO-209AB)		

△R <sub>thJC</sub> CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.016	0.012			
120°	0.019	0.020			
90°	0.025	0.027	$T_J = T_J$ maximum	K/W	
60°	0.036	0.037			
30°	0.060	0.060			

#### Note

• The table above shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC





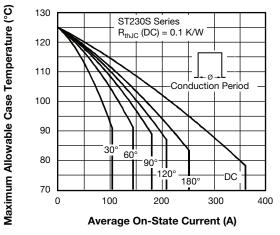


Fig. 2 - Current Ratings Characteristics

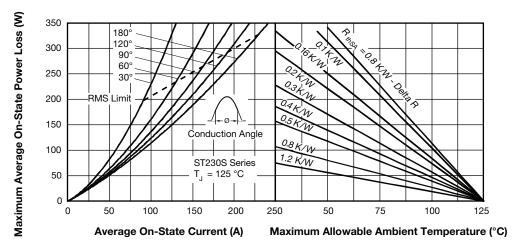


Fig. 3 - On-State Power Loss Characteristics

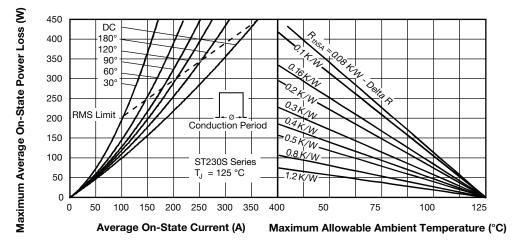


Fig. 4 - On-State Power Loss Characteristics

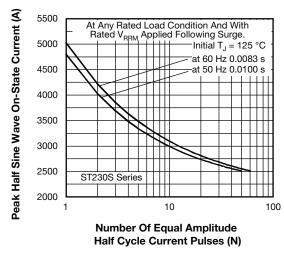


Fig. 5 - Maximum Non-Repetitive Surge Current

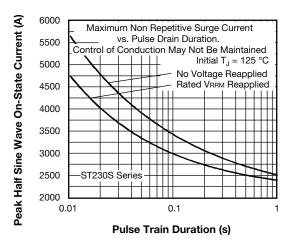


Fig. 6 - Maximum Non-Repetitive Surge Current

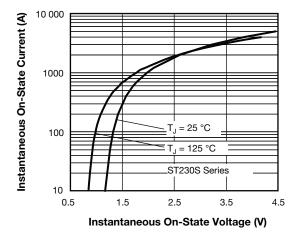


Fig. 7 - On-State Voltage Drop Characteristics

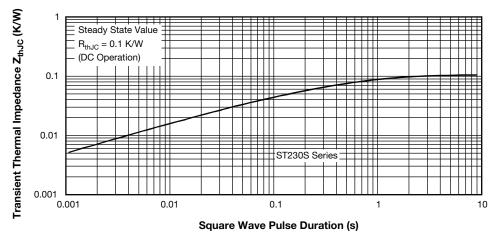


Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristics

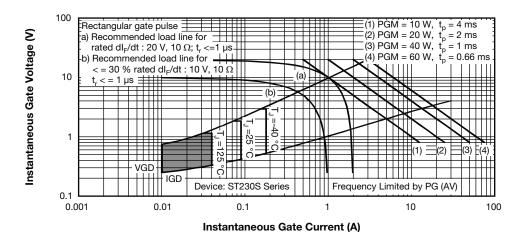
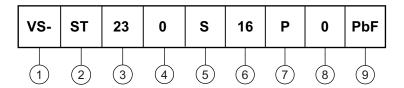


Fig. 9 - Gate Characteristics

#### **ORDERING INFORMATION TABLE**

**Device code** 



Vishay Semiconductors product

**Thyristor** 

Essential part number

0 = converter grade

S = compression bonding stud

Voltage code x 100 = V<sub>RRM</sub> (see Voltage Ratings table) 6

P = stud base 3/4"-16UNF2A threads

0 = eyelet terminals (gate and auxiliary cathode leads)

1 = fast-on terminals (gate and auxiliary cathode leads)

9 None = standard production

PbF = lead (Pb)-free

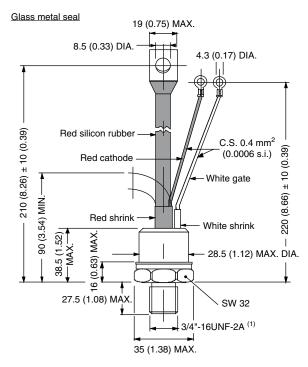
Note: For metric device M16 x 1.5 contact factory

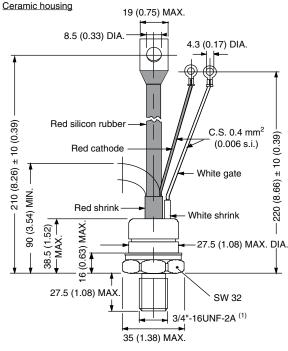
LINKS TO RELAT	ED DOCUMENTS
Dimensions	www.vishay.com/doc?95082

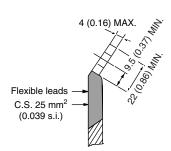


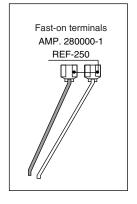
# TO-209AB (TO-93)

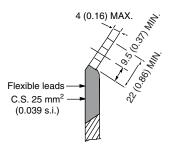
#### **DIMENSIONS** in millimeters (inches)











#### Note

(1) For metric device: M16 x 1.5 - length 21 (0.83) maximum



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